









	<h2 style="color: red;">FQD30N06TM</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQD30N06TM</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 22.7A DPAK-3</p> <p><b>Datenblätter:</b>  <a href="#">FQD30N06TM.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 38260 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQD30N06TM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 60V 22.7A DPAK-3
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	38260 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	2.5W (Ta), 44W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	22.7A (Tc)
Rds On (Max) @ Id, Vgs	45 mOhm @ 11.4A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	945pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)



















































FQD30N06TM ist neu im Original, Suche FQD30N06TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD30N06TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD30N06TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQD30N06TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 22.7A DPAK-3</p>	 <p><b>FQD30N06TF</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 22.7A DPAK</p>	 <p><b>FQD3N25TM</b> FAIRCHILD</p>	 <p><b>FQD3N30</b> FAI FQD3N30 FAI</p>
 <p><b>FQD3N25T</b> FAIRCHILD FQD3N25T FAIRCHILD</p>	 <p><b>FQD30N06TF</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 22.7A DPAK</p>	 <p><b>FQD30N06TF_F080</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 22.7A DPAK</p>	 <p><b>FQD30P06</b> FAIRCHILD FQD30P06 FAIRCHILD</p>

### heiße Teile

Mehr

 FQD2N60CTF_F080	 FQD2N60CTF_F080	 FQD2N60CTM	 FQD2N60CTM	 FQD2N60TM
 FQD2N60TM	 FQD2N65C	 FQD2N80TM	 FQD2N80TM	 FQD2N80TM-NL
 FQD2N90TF	 FQD2N90TF	 FQD2P25TF	 FQD2P25TF	 FQD30N06
 FQD30N06L	 FQD30N06LTF	 FQD30N06LTF	 FQD30N06LTM	 FQD30N06LTM
 FQD30N06TF	 FQD30N06TF	 FQD30N06TF_F080	 FQD30N06TF_F080	 FQD30N06TM
 FQD30P06	 FQD3N25T	 FQD3N30TF	 FQD3N30TF	 FQD3N30TM
 FQD3N30TM	 FQD3N40TM	 FQD3N40TM	 FQD3N50C	 FQD3N50C/CS
 FQD3N50CTF	 FQD3N50CTF	 FQD3N50CTM	 FQD3N50CTM	 FQD3N60C
 FQD3N60CS	 FQD3N60CTF	 FQD3N60CTM	 FQD3N60CTM_WS	 FQD3N60TF
 FQD3N60TF	 FQD3N60TM	 FQD3N60TM	 FQD3P20TF	 FQD3P20TF

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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